NSN 5961-01-363-4675

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4675 **Inclosure Material:** Glass **Overall Length:** 12.0 millimeters **Overall Diameter:** 3.0 millimeters **Function For Which Designed:** Rectifier **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20000.0 repetitive peak reverse voltage and 62.5 forward voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current peak and 5.00 milliamperes forward current, average **Capacitance Rating In Picofarads:** 1.0 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: